

Supporting Information

for

Effect of channel length on the electrical response of

carbon nanotube field-effect transistors to

deoxyribonucleic acid hybridization

Hari Krishna Salila Vijayalal Mohan^{*1}, Jianing An¹, Yani Zhang^{2,3}, Chee How Wong¹ and Lianxi Zheng^{*1,4}

Address: ¹School of Mechanical and Aerospace Engineering, Nanyang Technological University, 50 Nanyang Avenue, 639798, Singapore, ²Temasek Laboratories, Nanyang Technological University, 50 Nanyang Avenue, 639798, Singapore, ³Science and Technology on Thermostructural Composite Materials Laboratory, Northwestern Polytechnical University, 710072, Xi'an, PR China, and ⁴Department of Mechanical Engineering, Khalifa University of Science, Technology & Research (KUSTAR), P.O. Box 127788, Abu Dhabi, United Arab Emirates

Email: Hari Krishna Salila Vijayalal Mohan* - hari1@e.ntu.edu.sg; Lianxi Zheng* - Lianxi.zheng@kustar.ac.ae

* Corresponding author

Additional experimental data

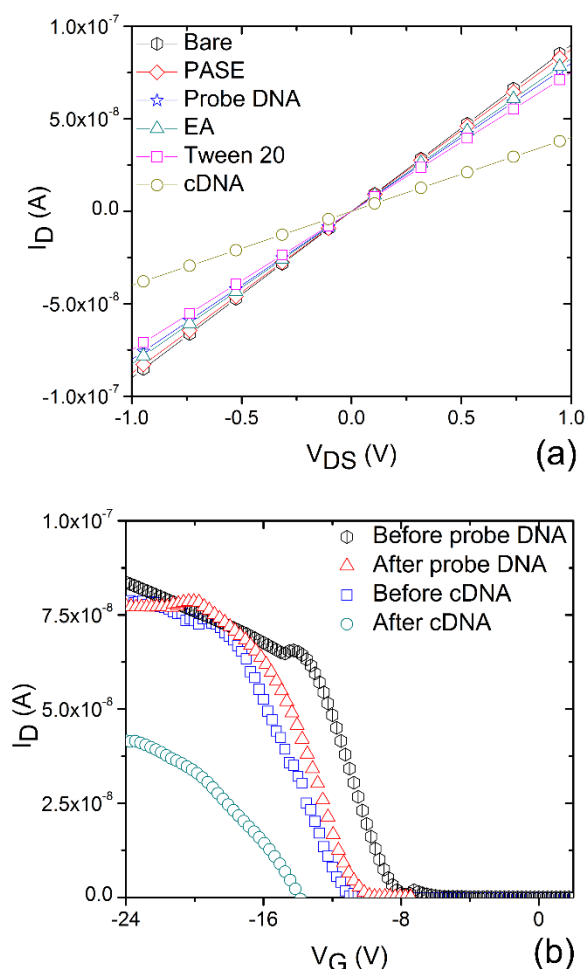


Figure S1: (a) I_D – V_{DS} and (b) I_D – V_G curves of SWCNT-based FETs showing the various functionalization steps with both channel and junction exposed to cDNA ($L = 300 \mu\text{m}$). The “before probe DNA” and “after probe DNA” I_D – V_G curves represent the PASE functionalization and probe DNA incubation steps, respectively. The “before cDNA” step corresponds to the incubation of probe DNA-immobilized FETs with EA and Tween 20. The “after cDNA” step represents the recording after incubation with cDNA.

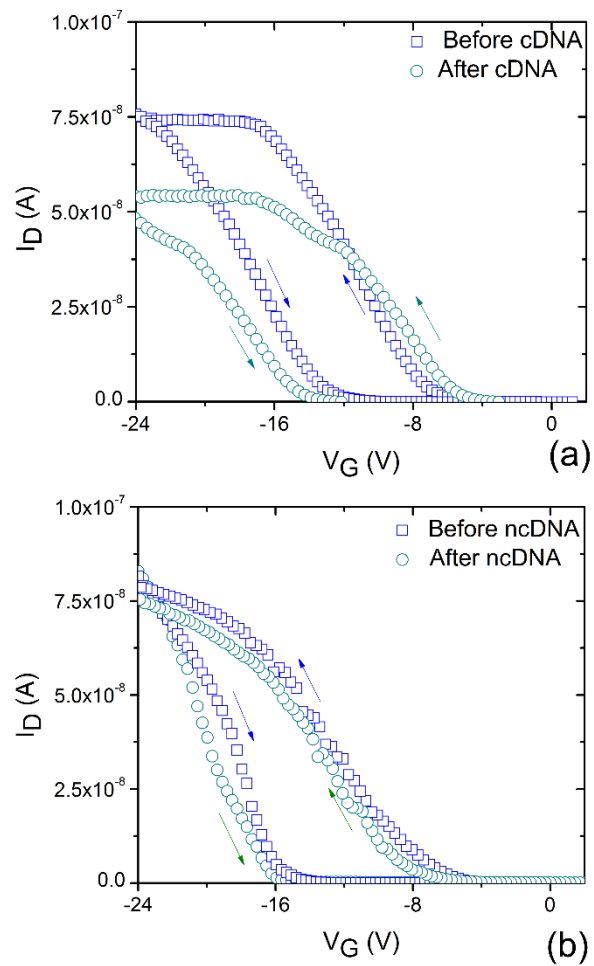


Figure S2: I_D - V_G plots of SWCNT-based FETs ($L = 300 \mu\text{m}$) with only the channel exposed to (a) cDNA and (b) ncDNA. The “before cDNA” step corresponds to the incubation of probe DNA-immobilized FETs with EA and Tween 20. The “after cDNA” step represents the recording after incubation with cDNA. The arrows indicate the direction of the gate voltage sweep.

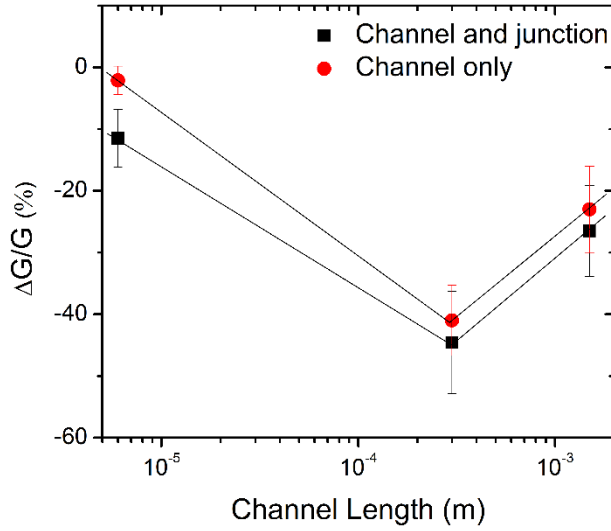


Figure S3: The variation in the conductance response for the devices with the channel and junction exposed ($\Delta G_{\text{on}}/G_{\text{on}}$) and devices with only the channel exposed ($\Delta G_{\text{ch}}/G_{\text{ch}}$) to cDNA, both as a function of L . $\Delta G_{\text{ch}}/G_{\text{ch}} \cong \Delta G_{\text{on}}/G_{\text{on}}$ for $L = 300 \mu\text{m}$ and $1500 \mu\text{m}$, which indicates the dominance of the change in channel resistance (ΔR_{ch}) after hybridization. $\Delta G_{\text{on}}/G_{\text{on}} > \Delta G_{\text{ch}}/G_{\text{ch}}$ for $L = 6 \mu\text{m}$, which indicates the additional contribution of the change in contact resistance (ΔR_{c}) to $\Delta G_{\text{on}}/G_{\text{on}}$ after hybridization. The solid lines are a guide to the eye.

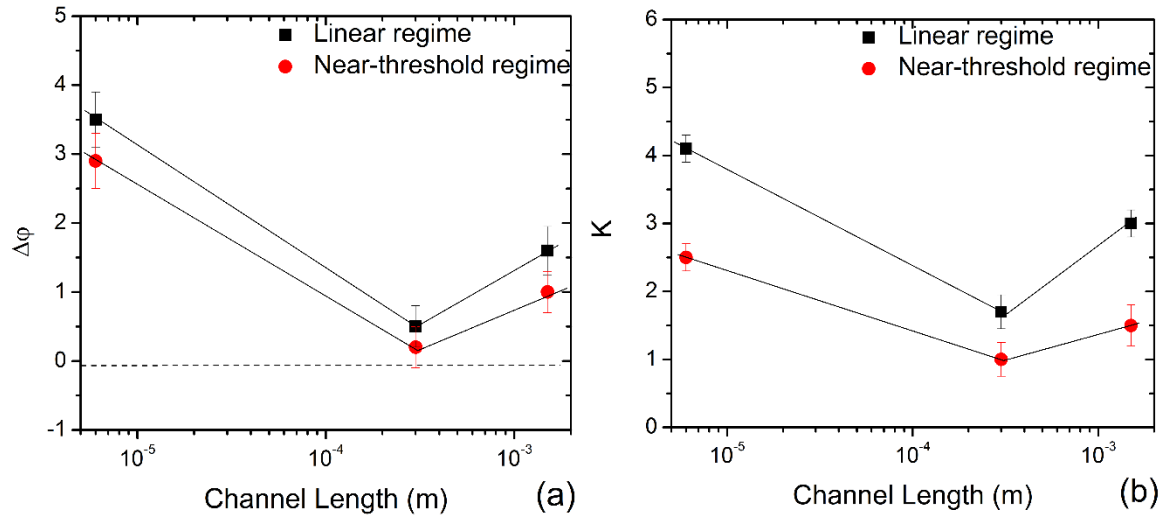


Figure S4: The variation in (a) $\Delta\phi$ and (b) K with L in the linear and near-threshold regimes for the reverse sweep. The solid lines are a guide to the eye.